



completed, which adversely impacts performance of the system.

[0004] From the foregoing discussion, there is a desire to provide a multi-port memory module in which the adverse impact on system performance by the refresh cycle is reduced.

## Summary of Invention

[0005] The invention relates generally to ICs with a memory module. In particular, the invention relates to efficiently refreshing a multi-port memory module. In one embodiment, the memory modules include first and second ports. A control block manages the memory accesses and refresh requests. In one embodiment, the control block includes a contention detection circuit that monitors the memory access requests through the access ports as well as the refresh operations. A refresh counter provides the sequence of addresses of rows of memory cells that are to be refreshed. The addresses of memory accesses rows are provided through the access ports. The address decoder within each port activates the row either for a refresh or for a memory access. The contention circuit ensures that a refresh operation is allocated to a port which is not used for a memory access at the same time.

## Brief Description of Drawings

[0006] Fig. 1 shows a block diagram of a dual port memory;

[0007] Fig. 2 shows a particular memory cell of the memory cell array shown in Figure 1;

[0008] Fig. 3 shows a diagram of a refresh cycle;

[0009] Fig. 4 shows a functional diagram of a refresh control circuit; and

[0010] Fig. 5 shows an alternative timing diagram of a refresh cycle.

## Detailed Description

[0011] Fig. 1 shows a block diagram of a dual-port memory module in accordance with one embodiment of the invention. The memory module, for example, could be embedded into an IC, such as a DSP. Other types of ICs, such as memory ICs, are also useful. As shown in Fig. 1, the memory module includes a memory array 1 which can be accessed through first and second ports 2 and 3 (port A and port B). Providing a





control circuit comprises a control block 61. The control block receives a system clock signal which controls the function of the memory module. The IC can have two modes of operation, power down or normal. The operating modes of the IC can be controlled by the PD signal. In one embodiment, a second clock signal is provided to the control block. The second clock signal is generated by, for example, an oscillator 60.

[0019] In one embodiment, the control generates a refresh enable signal (RE). The refresh control signal can be synchronized with either of the clock signals. The RE signal controls a refresh address counter 62 that provides the sequence of the row addresses of the memory cell array. The refresh address counter outputs the refresh address RR. In one embodiment, if the IC is in power down mode (e.g., PD = 1), the refresh is activated using the refresh clock from oscillator 60 by function block 63. In the power down mode, the IC is not susceptible to access requests through ports A and B.

[0020] When the IC is in normal operation (e.g., PD = 0), the refresh address RR is forwarded to function block 64 which performs contention detection. Contention detection is performed, in one embodiment, by comparing the address of the access and refresh address. Function block 64 is provided with any addresses ADRA, ADRB subject to an access through port A or B and the port select signals CSA, CSB. During a refresh operation, four different contention scenarios or states can occur, as shown in Table 1.

[0021]

[t1]

**Table 1**

State	Port A	Port B	Refresh allocation
1	—	—	Port A/ Port B
2	√	—	Port B
3	—	√	Port A
4	√	√	Port B

State 1 represents the case where no memory access is requested during a refresh

request. In the absence of a contention between a refresh and a memory access, the row addressed by the refresh counter can be refreshed through either of the ports. In a preferred embodiment, one of the ports can be dedicated for refreshing (e.g., port A) when no contention occurs.

[0022] State 2 represents the case where a memory access is requested through port B while a refresh is requested. The addresses of the refresh and access are compared. If the addresses of the access and refresh are to different rows, the access is conducted through port B while the refresh operation is allocated to port A. The row corresponding to the refresh address is refreshed through port A. Alternatively, a memory access through port B is requested simultaneously with a refresh request, as represented by state 3. In such a case, the memory access is performed through port B while the refresh is conducted through port A if the addresses of the access and refresh are to different rows.

[0023] In one embodiment, for states 2 or 3, where an access is a read access to the same row which is to be refreshed, the refresh is suppressed or omitted. All the memory cells of the row are read. However, only data from the selected cell or cells of the row is output. The reading of the cells effectively refreshes the row. For a write operation, the non selected cells of the row are read without outputting their data. Alternatively, the refresh can be performed from one port while the access is performed from the other port.

[0024] In the case where memory accesses via both ports are requested along with a refresh request (state 4), one of the accesses is performed through one of the ports while a refresh is performed through the other port if neither of the accesses is to the row which is to be refreshed. The second access is delayed with a wait signal until the refresh is completed. The wait signal also informs that the access to other port is delayed. For example, the access to port A is performed, the access to port B is delayed, and the refresh is performed through port B. Assigning priority to port B for memory accesses in such a case is also useful. The priority of access to the ports can be rotated through the use of a flag.

[0025] In the case where one of the accesses is to a row which is to be refreshed, the refresh operation can be disabled. Both rows can be accessed. In the case where a

write access is performed to a memory cell on the row which is to be refreshed, the selected memory cell is written to while the other memory cells of the row are read.

[0026] When port A or port B is used for the refresh, the row decoder in the respective port A or B is provided with the address of the row from the refresh address counter.

[0027] The function block 64 performing the function of contention detection and address comparison performs the following decisions:

[0028] 1. When  $RE = 0$ , then there is no conflict between port access and refresh. The row address ADRA is provided to the first decoder through its input ADRA', the row address ADRB is provided to the second decoder through its input ADRB'. Decoders activate one of the wordlines to read or write data from or into one or several of the memory cells of a row.

[0029] 2. When  $RE = 1$  and none of the ports A or B is selected for an external access, the refresh address RR is provided to one of ports A and B through one of their inputs ADRA' and ADRB'.

[0030] 3. When  $RE = 1$  and only port A is selected for an external access, the row address ADRA for the access through port A is provided to first row decoder. The refresh address RR is provided to second row decoder to perform the refresh.

[0031] 4. When  $RE = 1$  and only port B is selected for an external access, the row address ADRB for the access through port B is provided to the second row decoder. The refresh address RR is provided to first row decoder for refresh.

[0032] 5. When  $RE = 1$  and both ports A and B are selected for an external access, the address ADRA for access of port A is provided to first row decoder to perform the requested access. The refresh address RR from refresh address counter 62 is provided to second row decoder to perform the refresh. In addition, a wait cycle signal WSB is issued by refresh control block 4 to delay the read/write address with respect to row address ADRB by one cycle so that the refresh cycle can be performed through the second row address decoder of port B.

[0033] In all of the cases 3 through 5 it is assumed that the refresh address RR from refresh address counter 62 is different from the read/write addresses ADRA, ADRB. If

this is not the case and the refresh address RR is equal to one of the row addresses ADRA, ADRB which are intended for an access, the refresh of the particular row is suppressed. Also in case 5 the issuance of the wait cycle signal WSB is omitted. Instead, the access is performed. The function block 64 contains a comparator that compares the row addresses of memory cells to be accessed for read/write and the row address for a refresh.

[0034] In Fig. 5 an alternative time scheme is shown to perform the periodic refresh of the memory cell array. The time period between the pulses 71 and 72 of the refresh enable signal RE is the same as in Fig. 3. The refresh enable signal, however, has a sequence of shorter pulses as compared to Fig. 3 and is repeated several times. The refresh enable signal is distributed over the period R over N pulses. Whereas all N rows are refreshed in time period 0, T according to Fig. 3, only one of the N rows is refreshed in one of the pulses (e.g., 71 in Fig. 5).

[0035] While the invention has been particularly shown and described with reference to various embodiments, it will be recognized by those skilled in the art that modifications and changes may be made to the present invention without departing from the spirit and scope thereof. The scope of the invention should therefore be determined not with reference to the above description but with reference to the appended claims along with their full scope of equivalents.